

High Temperature, High Voltage Performance Characteristics

GENERAL SPECIFICATIONS

Working Voltage:

C0G	50, 100, 200, 500, 1k, 2k, 3k, 4k, 5k, 7.5k, 10k, 15k, 20k
X7R	50, 100, 200, 500, 1k, 2k, 3k, 4k, 5k, 7.5k, 10k, 15k, 20k, 30k, 40k, 50k
X5U	3k, 4k, 5k, 7.5k, 10k, 15k, 20k

Temperature Characteristics:

C0G	0 + 30 PPM / °C from -55°C to +125°C (1)
X7R	+15% from -55°C to +125°C
X5U	+22%, -56% from -55°C to +85°C

Capacitance Tolerance:

C0G	+0.5pF, +1%, +2%, +5%, +10%
X7R	±5%, ±10%, ±20%, +80% / -20%, +100% / -0%
X5U	±5%, ±10%, ±20%, +80% / -20%, +100% / -0%

Construction:

Epoxy encapsulated - meets flame test requirements of UL Standard 94V-0.
High-temperature solder - meets EIA RS-198, Method 302, Condition B (260°C for 10 seconds)

Termination Material:

Check individual Series: Part Number and Ordering Information for Termination Materials offered in each series.

Solderability:

MIL-STD 202, Method 208
(Test Method: ANSI/J-STD-002)
Test A for through-hole mount and surface mount leaded.
Test B for surface mount leadless components.

Terminal Strength:

MIL-STD 202, Method 208, Condition A (2.3kg or 5 lbs)

Resistance to Solvents:

MIL-STD 202, Method 215

Resistance to Soldering Heat:

MIL-STD 202, Method 210, Test Condition C

ELECTRICAL

Capacitance @ 25°C:

Within specified tolerance and following test conditions per MIL-STD 202, Method 305.
C0G, X7R & X5U
> 100pF with 1.0 vrms @ 1 kHz with 1.0 vrms
< 100pF with 1.0 vrms @ 1 MHz with 1.0 vrms

Dissipation Factor @ 25°C:

Same test conditions as capacitance.
C0G - 0.15% maximum
X7R - 2.5% maximum
X5U - 2.5% maximum

Insulation Resistance @25°C:

MIL-STD 202, Method 302
C0G & X7R:
100 gigohm or 1 gigohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.
X5U:
10 gigohm or 100 megohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.

Dielectric Withstanding Voltage:

MIL-STD 202, Method 301
<200V test @ 250% of rated voltage
500V to 1250V test @ 150% of rated voltage
>1251V test @ 120% of rated voltage

ENVIRONMENTAL

Vibration:

MIL-STD 202, Method 204, Condition D (20g)

Shock:

MIL-STD 202, Method 213, Condition I (100g)

Life Test:

MIL-STD 202, Method 108

<200V

C0G - 200% rated voltage @ +125°C
X7R - 200% rated voltage @ +125°C

>500V

C0G - rated voltage @ +125°C
X7R - rated voltage @ +125°C
X5U - rated voltage @ +85°C

Post Test Limits @ 25°C are:

Capacitance Change:

C0G (< 200V) - +3% or 0.25pF, whichever is greater.
C0G (> 500V) - +3% or 0.50pF, whichever is greater.
X7R - +20% of initial value (2)

Dissipation Factor:

C0G - 0.25% maximum
X7R & X5U - 3.0% maximum

Insulation Resistance:

C0G & X7R:
100 gigohm or 1 gigohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.

X5U:

10 gigohm or 100 megohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.

Moisture Resistance:

MIL-STD 202, Method 106

Post Test Limits @ 25°C are:

Capacitance Change:

C0G (< 200V) - +3% or 0.25pF, whichever is greater.
C0G (> 500V) - +3% or 0.50pF, whichever is greater.
X7R - +20% of initial value (2)

Dissipation Factor:

C0G - 0.25% maximum
X7R & X5U - 3.0% maximum

Insulation Resistance:

C0G & X7R:
100 gigohm or 1 gigohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.

X5U:

10 gigohm or 100 megohm x uF, whichever is less.
<500V test @ rated voltage, >1kV test @ 500V.

Thermal Shock:

MIL-STD 202, Method 107, Condition A

C0G & X7R: -55°C to 125°C

X5U: -55°C to 85°C

- (1) +53 PPM -30 PPM/ °C from +25°C to -55°C, +60 PPM below 10pF.
- (2) X7R & X5U dielectrics exhibit aging characteristics; therefore, it is highly recommended that capacitors be deaged for 2 hours at 150°C and stabilized at room temperature for 48 hours before capacitance measurements are made.

	HIGH TEMPERATURE	HIGH VOLTAGE
MILITARY & AEROSPACE		
Avionics	X	X
Radar Systems	X	X
Telemetry, Data Tx/Rx		X
Control Systems	X	
MEDICAL		
.5 to 1.5 Tesla MR1 &		X
NM1 Tuning Coils		X
1 to 3 Tesla MR1 Gradient		X
Coils & Magnetic Rings		X
CT-Scanner		X
Medical MRI		X
X-Ray Generator	X	X
SEMICONDUCTOR		
RF Tuning Networks		X
RF Power Supplies		X
Semiconductor Manufacturing	X	
SECURITY		
Handheld Scanners		X
Intruder Detection Systems		X
Luggage Scanners		X
Metal/Explosive Detector		X
OTHER		
LCD Backlight Inverter		X
Electric Ballast for CFL	X	X
Electric Ballast for Fluorescent Lamp	X	X
Measurement Equipment	X	X
Microwave/Convection Ovens	X	X
POWER SUPPLY		
HV Power Supply	X	X
Power Station Equipment		X
Power Supply for Air Conditioner, Washing Machine		X
Inverter Power Supply-AC	X	
TELECOM		
Base Station Power amps		X
Broadcasting Equipment		X
MODEM		
DAA Modem		X
xDSL Modem		X
LAN, Router, HUB, Switches		X
RF Power Amplifiers		X
INDUSTRIAL		
Oil Rigging, Down Hole, Mining	X	X

KEMET High Voltage Technical Summary

	ELECTRICAL			ENVIRONMENTAL	MECHANICAL
	Voltage Range	Capacitance Range	Dissipation Factor	Operating Temperature Range	Configuration

HIGH VOLTAGE

Radial Conformally Coated					
Std	C0G/X7R: 500 to 10k VDC	C0G:12 pF - .330µF X7R: 220 pF - 5.6 µF	C0G: 0.15% max X7R: 2.5% max	C0G: -55°C to + 125°C X7R: -55°C to + 125°C	Radial
Mil-PRF-49467 Equivalent	C0G/X7R: 600 to 5k VDC	C0G: 12 pF - .68 µF X7R: 27 pF - .47 µF	C0G: 0.15% max X7R: 2.5% max	C0G/X7R: -55°C to + 125°C	Radial
Space Quality	C0G/X7R: 500 to 10k VDC	C0G/X7R: 560 pF - 2.20µF	C0G: 0.15% max X7R: 2.5% max	C0G/X7R: -55°C to + 125°C	Radial
Ceramic Surface Mount Chip					
Military	C0G/X7R: 500 to 5k VDC	C0G: 12 pF - .10 µF X7R: 270 pF -2.50 µF	C0G: 0.15% max X7R: 2.5% max	C0G/X7R: -55°C to + 125°C	Chip
Leaded Chips J or L lead	C0G/X7R: 500 to 10k VDC	C0G: 12 pF-.330 µF X7R: 220 pF-5.6 µF	C0G: 0.15% max X7R: 2.5% max	C0G/X7R: -55°C to + 125°C	Leaded Chip J or L Lead
Disc	C0G/X5U: 3k to 20k VDC, X7R:3k to 50k VDC	C0G: 1.2 pF-236 pF X7R: 10 p -7400 pF X5U: 80 pF-17300 pF	C0G: 0.15% max X7R: 2.5% max X5U: 2.5% max	C0G/X7R: -55°C to + 125°C X5U: -55°C to + 85°C	Disc
Disc Stack	C0G/X7R/X5U: 5k to 20k VDC	C0G: 1.2 pF-141 pF X7R: 37 pF-4400 pF X5U: 80 pF-10400 pF	C0G: 0.15% max X7R: 2.5% max X5U: 2.5% max	C0G/X7R: -55°C to + 125°C X5U: -55°C to + 85°C	Disc Stack

HIGH TEMPERATURE

Hi Temp (HT/HP)	100 to 200 VDC	-C0G: 22 pF-.100 µF X7R:1000 pF-1.0µF	C0G 0.15% X7R Type 2.0% X7R 2.50%	-55°C to + 200°C	Axial/Radial
Hi Temp Hi Volt (HV)	500 to 4000 VDC	C0G: 390 pF-.015 µF X7R:1400 pF- .270 µF	C0G 0.15% X7R Type 2.0% X7R 2.50%	-55°C to + 200°C	Radial
Ceramic Cased Capacitor					
Std 125°C (SCR/SRR/SCA/SRA)	50 to 200 VDC	C0G: 1.0 pF- .12 µF X7R:100 pF- 6.8 µF	C0G 0.15% X7R 2.50%	-55°C to + 125°C	Axial/Radial
200°C (ACR/ARR/ACA/ARA)	50 to 100 VDC	C0G: 1.0 pF- .12 µF X7R:100 pF- 3.3 µF	C0G 0.15% X7R 2.50%	-55°C to + 200°C	Axial/Radial
260°C (TCR/TRR/TCA/TRA)	50 to 100 VDC	C0G: 1.0 pF- .12 µF X7R:100 pF- 3.3 µF	C0G 0.15% X7R 2.50%	-55°C to + 260°C	Axial/Radial
Hi Temp Hi Volt (VCR/VRR)	500 to 5000 VDC	C0G: 10 pF-.056 µF X7R:330 pF-1.2µF	C0G 0.15% X7R 2.50%	-55°C to + 200°C	Radial

DIELECTRIC COMPARISONS

Features	Ultra Stable	Semi-Stable High Voltage	Semi-Stable Hi-Temp	Temp/Volt Dependent
Dielectric Type	C0G (NP0)	X7R	X7R type	X5U
Temperature Coefficient	0 ±30ppm/°C	±15%	+15/-40%	+22-56%
Operating Temp. Range	-55 to +200°C	-55 to +125°C	-55 to +200°C	-55 to +125°C
Dissipation Factor	0.1% max.	2.5% max.	2.0% max.	2.5% max.
Aging Rate	None	-2.0% max/dec. hour	-2.0% max/dec. hour	-2.0% max/dec. hour
Voltage Range	25 to 20k VDC	50 to 50k VDC	25 to 4k VDC	Up to 20K VDC
Standard Tolerance	J, K, M	K, M, P, Z	K, M, P, Z	M, P, Z
Coefficient of Thermal Expansion @ 25°C	9 X 10-6 IN/IN °C	11 X 10-6 IN/IN °C	11 X 10-6 IN/IN °C	11 X 10-6 IN/IN °C

**TYPICAL INSULATION RESISTANCE VS. TEMP (°C)
FOR C0G, NP0 & X7R DIELECTRICS**

